

Features

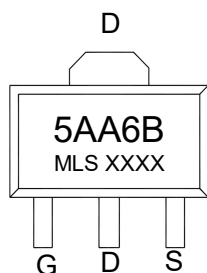
- Fast switching capability
- 100% avalanche tested
- Improved dv/dt capability

Product Summary

V_{DS}	$R_{DS(ON)}$ MAX	I_D MAX
500V	25Ω@10V	0.6A

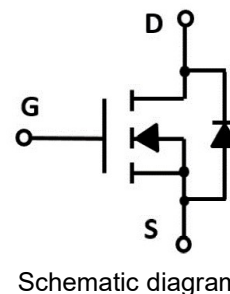
Application

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply (UPS)
- Power Factor Correction (PFC)



5AA6B : Device code
 XXXX : Code

Marking and pin assignment



Schematic diagram



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
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Common Ratings (TC=25°C Unless Otherwise Noted)

V_{DS}	Drain-Source Breakdown Voltage	500	V
V_{GS}	Gate-Source Voltage	±30	V
T_J	Maximum Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-50 to 155	°C
I_S	Diode Continuous Forward Current	$T_c=25^{\circ}C$ 0.6	A

Mounted on Large Heat Sink

I_{DM}	Pulse Drain Current Tested	$T_c=25^{\circ}C$ 2.4	A
I_D	Continuous Drain Current	$T_c=25^{\circ}C$ 0.6	A
P_D	Maximum Power Dissipation	$T_c=25^{\circ}C$ 0.5	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	150	°C/W

Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MZ5AA6B	SOT-89-3L	5AA6B	1,000	10,000	40,000	7"reel

Electrical Characteristics (T _J =25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
B _{V(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	500	–	–	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =500V, V _{GS} =0V	–	–	1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±30V, V _{DS} =0V	–	–	±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1	–	2.5	V
R _{DS(on)}	Drain-Source On-State Resistance	V _{GS} =10V, I _D =0.3A	–	16	25	Ω
Dynamic Electrical Characteristics @ T _J = 25°C (unless otherwise stated)						
C _{ISS}	Input Capacitance	V _{DS} =25V, V _{GS} =0V, f=1MHz	–	51	–	pF
C _{OSS}	Output Capacitance		–	10	–	pF
C _{RSS}	Reverse Transfer Capacitance		–	1.2	–	pF
Switching Characteristics						
Q _g	Total Gate Charge	V _{DD} =400V, I _D =0.6A, V _{GS} =10V	–	5	–	nC
Q _{gs}	Gate Source Charge		–	1.5	–	nC
Q _{gd}	Gate Drain Charge		–	1.4	–	nC
t _{d(on)}	Turn-on Delay Time	V _{DD} =250V, I _D =0.3A, V _{GS} =10V, R _G =25Ω	–	2.2	–	nS
t _r	Turn-on Rise Time		–	36	–	nS
t _{d(off)}	Turn-Off Delay Time		–	18	–	nS
t _f	Turn-Off Fall Time		–	65	–	nS
Source- Drain Diode Characteristics						
V _{SD}	Forward on voltage	T _J =25°C, I _S =0.6A	–	–	1.2	V

Typical Operating Characteristics

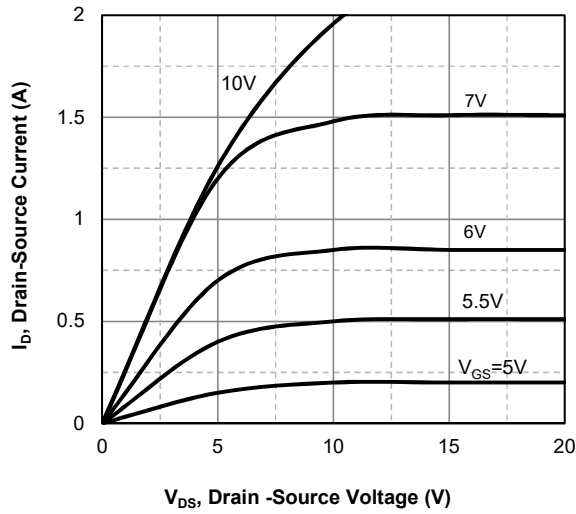


Fig1. Typical Output Characteristics

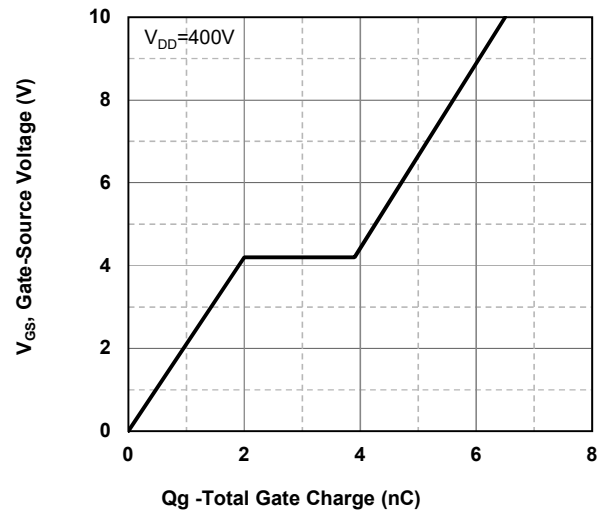


Fig2. Typical Gate Charge Vs. Gate-Source Voltage

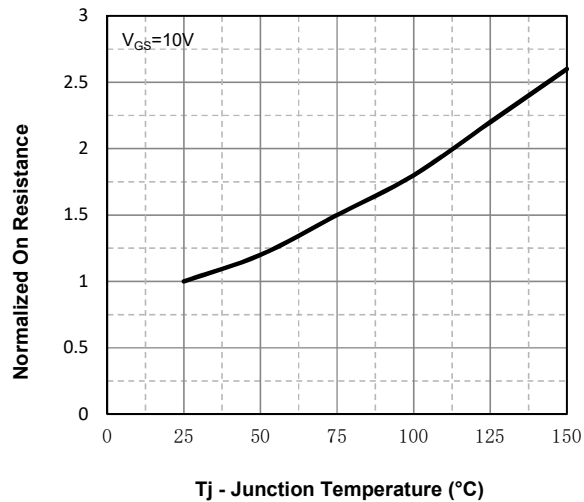


Fig3. Normalized On-Resistance Vs. Temperature

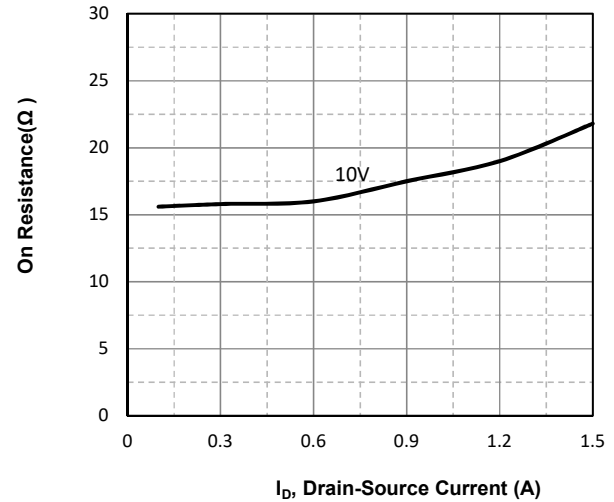


Fig4. On-Resistance Vs. Drain-Source Current

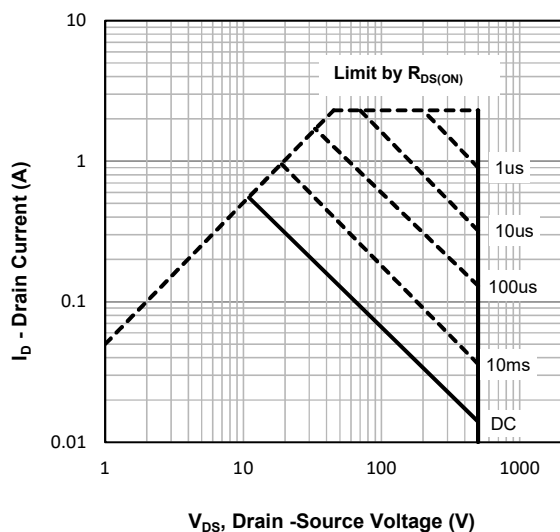


Fig5. Maximum Safe Operating Area

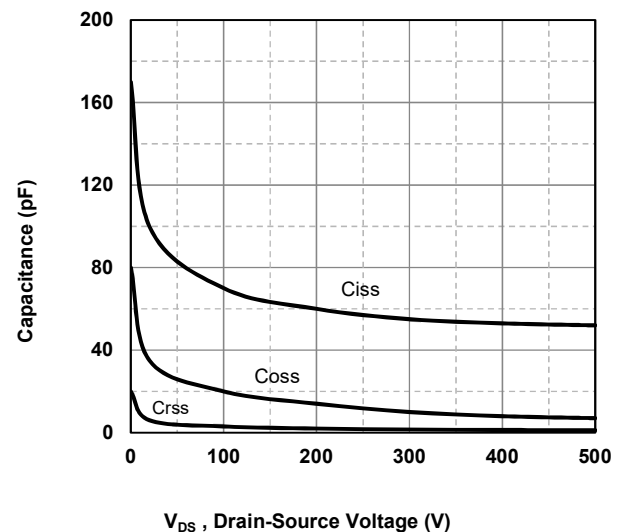
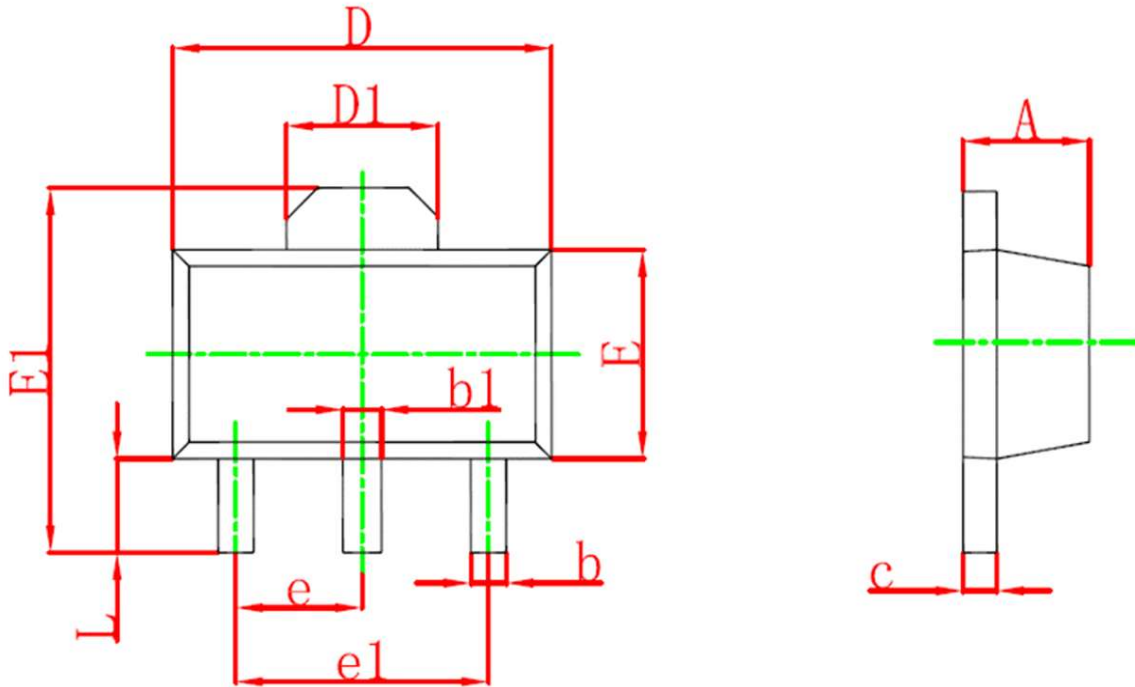


Fig6 Typical Capacitance Vs. Drain-Source Voltage

SOT-89-3L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions in Inches	
	Min	Max	Min	Max
A	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.400	0.580	0.016	0.023
c	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.550 REF		0.061 REF	
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
e	1.500 TYP		0.060 TYP	
e1	3.000 TYP		0.118 TYP	
L	0.900	1.200	0.035	0.047